## Electronic Version v1.1

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CONVEYING PARTY DATA									
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Tsann Lin				11/16/2007					
Daniele Mauri				11/16/2007					
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Property Type		119/1	Number						
Application Number: 11941763 674 767 767 767 767 767 767 767 767 767									
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## ASSIGNMENT

## METHOD FOR FORMING AN MgO BARRIER LAYER IN A TUNNELING MAGNETORESISTVE (TMR) DEVICE

and executed a Declaration and Power of Attorney for a United States patent application therefor on:

1. (\ / [	o (	0	2. 11/16/07	]
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Whereas, HITACHI GLOBAL STORAGE TECHNOLOGIES NETHERLANDS B.V., having a place of business at Locatellikade 1, Parnassustoren, 1076 AZ Amsterdam, The Netherlands (hereafter called HITACHI), desires to acquire the entire right, title and interest in the said application and invention, and to any United States and foreign patents to be obtained therefor;

Now therefore, for a valuable consideration, receipt whereof is hereby acknowledged, we, the above named, hereby sell, assign, and transfer to HITACHI, its successors and assigns, the entire right, title and interest in the said application and invention therein disclosed for the United States and foreign countries, and all rights of priority resulting from the filing of said United States application, and we request the Commissioner of Patents to issue any Letters Patent granted upon the inventions set forth in said application to HITACHI, its successors and assigns; and we hereby agree that HITACHI may apply for foreign Letters Patent on said invention and we will execute all papers necessary in connection with the United States and foreign applications when called upon to do so by HITACHI.

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## PATENT REEL: 020128 FRAME: 0455

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